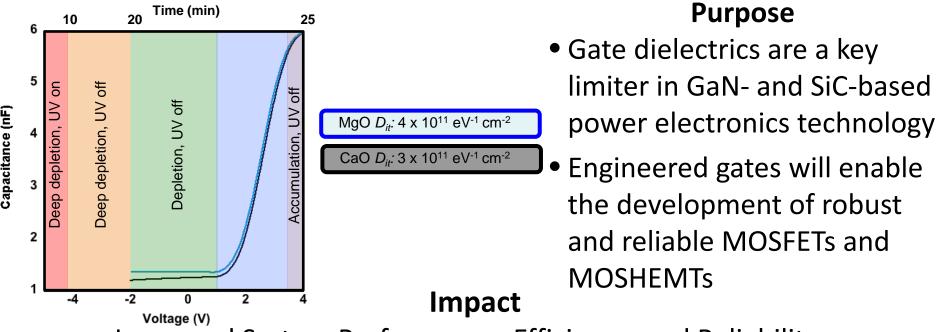
Reliable High-Performance Gate Oxides for Wide Band Gap Devices



Jon Ihlefeld and Stan Atcitty, Sandia National Laboratories jihlefe@sandia.gov, (505) 844-3162, satcitt@sandia.gov, (505) 284-2701



- Increased System Performance, Efficiency, and Reliability
- Reduced System Cost
- Reduced Power Electronics Size

Funded by the U.S. DOE Energy Storage Systems Program through Sandia National Laboratories. Sandia National Laboratories is a multi-program laboratory managed and operated by Sandia Corporation, a wholly owned subsidiary of Lockheed Martin Corporation, for the U.S. Department of Energy's National Nuclear Security Administration under contract DE-AC04-94AL85000. SAND2015-7534 C